

**Surface Mount Attenuator
10 Watts, 3dB**



Features:

- RoHS Compliant
- 10 Watts
- Low Cost
- DC – 6.0GHz
- Al₂O₃ Ceramic
- Non-Nichrome Resistive
- Low VSWR
- 100% Tested

Description:

The XRA10AA3SES is a high performance Alumina (Al₂O₃) chip attenuator intended as a cost competitive alternative to Beryllium Oxide (BeO). It is designed particularly for LTE and 5G wireless communication frequency bands. The high power handling makes the part ideal for inter-stage matching, directional couplers, and for use in isolators. The attenuator is also RoHS compliant!

General Specifications:

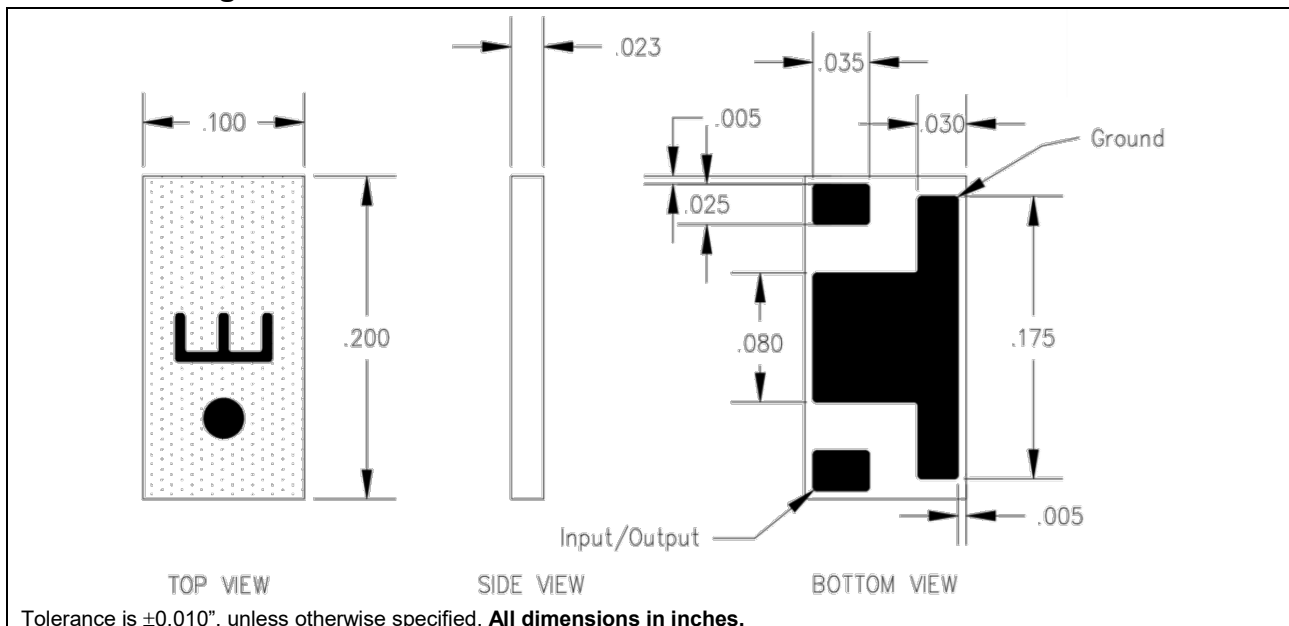
Resistive Element	Thick film
Substrate	Al ₂ O ₃ Ceramic
Terminal Finish	Matte Tin over Nickel Barrier
Operating Temperature	-55 to +150°C (see de-rating chart)

Electrical Specifications:

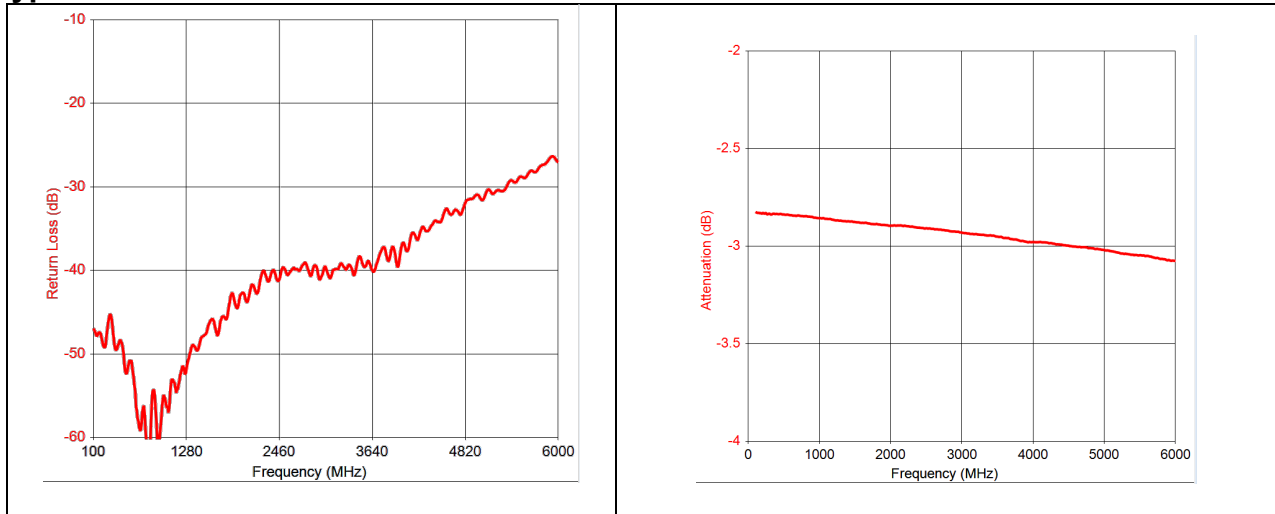
Attenuation Value:	3.0 ± 0.3 dB
Power:	10 Watts
Frequency Range:	DC – 6.0GHz
Input Return Loss:	20dB

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.**

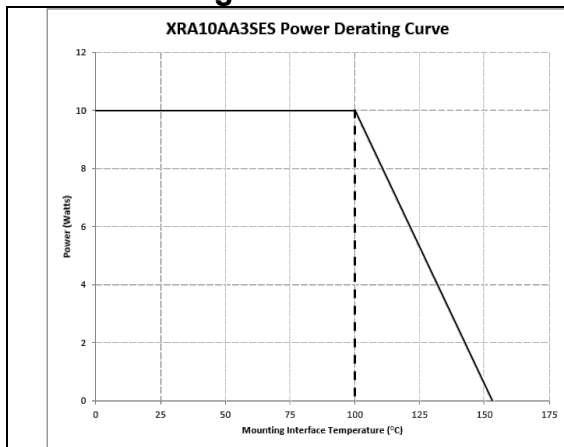
Outline Drawing:



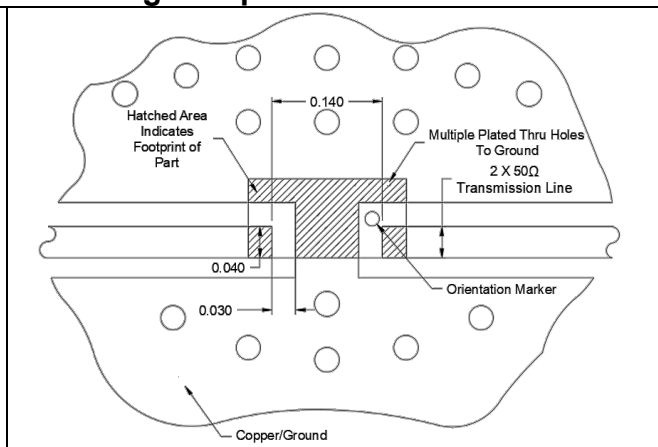
Typical Performance:



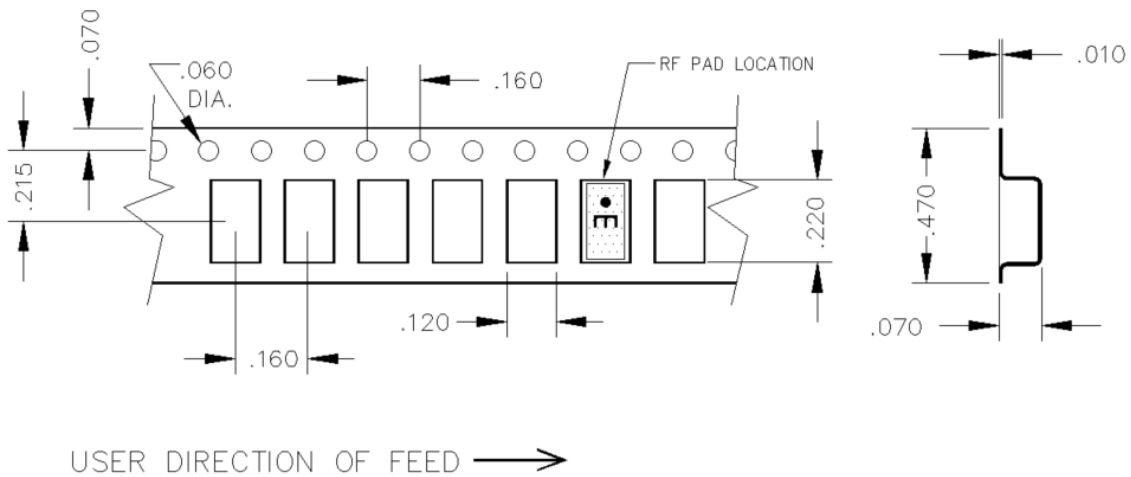
Power de-rating:



Mounting Footprint:



Tape & Reel:



Contact us:
rf&s_support@ttm.com